NSN 5961-01-027-4290

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-027-4290
Inclosure Material:
Plastic
Overall Length:
0.390 inches
Overall Height:
0.187 inches
Overall Width:
0.320 inches
Mounting Facility Quantity:
1
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
4.000 amperes drain current pascal
Maximum Operating Tempurature Per Measurement Point:
115.0 degrees celsius junction
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0